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- Operating Range 2-V to 5.5-V V_{CC}
- EPIC[™] (Enhanced-Performance Implanted CMOS) Process
- High Latch-Up Immunity Exceeds 250 mA Per JESD 17
- Package Options Include Plastic Small-Outline (DW), Shrink Small-Outline (DB), Thin Shrink Small-Outline (PW), and Ceramic Flat (W) Packages, Ceramic Chip Carriers (FK), and Standard Plastic (N) and Ceramic (J) 300-mil DIPs

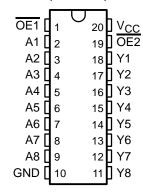
description

The 'AHC541 octal buffers/drivers are ideal for driving bus lines or buffer memory address registers. These devices feature inputs and outputs on opposite sides of the package to facilitate printed circuit board layout.

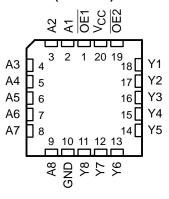
The 3-state control gate is a two-input AND gate with active-low inputs so that if either output-enable (OE1 or OE2) input is high, all corresponding outputs are in the high-impedance state. The outputs provide noninverted data when they are not in the high-impedance state.

The SN54AHC541 is characterized for operation over the full military temperature range of –55°C to 125°C. The SN74AHC541 is characterized for operation from –40°C to 85°C.

SN54AHC541 . . . J OR W PACKAGE SN74AHC541 . . . DB, DW, N, OR PW PACKAGE (TOP VIEW)



SN54AHC541 . . . FK PACKAGE (TOP VIEW)



FUNCTION TABLE (each buffer/driver)

	INPUTS	OUTPUT	
OE1	OE2	Α	Y
L	L	L	L
L	L	Н	Н
Н	X	Χ	Z
Х	Н	Χ	Z

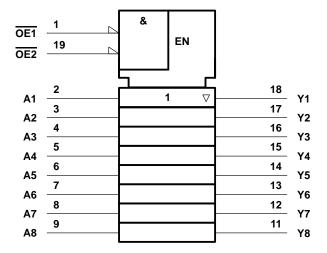


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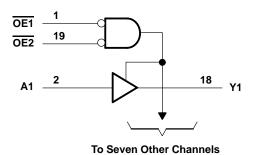


logic symbol†



[†] This symbol is in accordance with ANSI/IEEE Std 91-1984 and IEC Publication 617-12.

logic diagram (positive logic)



absolute maximum ratings over operating free-air temperature range (unless otherwise noted)‡

Supply voltage range, V_{CC}	DC)): DB package DW package N package PW package	$\begin{array}{llllllllllllllllllllllllllllllllllll$
Storage temperature range, T _{Stg}		–65°C to 150°C

[‡] Stresses beyond those listed under "absolute maximum ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under "recommended operating conditions" is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.



NOTES: 1. The input and output voltage ratings may be exceeded if the input and output current ratings are observed.

^{2.} The package thermal impedance is calculated in accordance with JESD 51, except for through-hole packages, which use a trace length of zero.

recommended operating conditions (see Note 3)

			SN54A	SN54AHC541		HC541	UNIT	
			MIN	MAX	MIN	MAX	UNII	
Vcc	Supply voltage		2	5.5	2	5.5	V	
		V _{CC} = 2 V	1.5		1.5			
VIН	V _{IH} High-level input voltage	V _{CC} = 3 V	2.1		2.1		V	
		$V_{CC} = 5.5 \text{ V}$	3.85		3.85			
		V _{CC} = 2 V		0.5		0.5		
V _{IL} Low-level input voltage	V _{CC} = 3 V		0.9		0.9	V		
		V _{CC} = 5.5 V		1.65		1.65		
٧ı	Input voltage		0	5.5	0	5.5	V	
٧o	Output voltage		0	VCC	0	VCC	V	
		V _{CC} = 2 V		-50		-50	μΑ	
IOH	High-level output current	$V_{CC} = 3.3 \text{ V} \pm 0.3 \text{ V}$		-4		-4	mA	
		$V_{CC} = 5 V \pm 0.5 V$		-8		-8	IIIA	
		V _{CC} = 2 V		50		50	μΑ	
lOL	Low-level output current	$V_{CC} = 3.3 \text{ V} \pm 0.3 \text{ V}$		4		4	mΛ	
		$V_{CC} = 5 V \pm 0.5 V$		8		8	mA	
Δt/Δν	Input transition rise or fall rate	$V_{CC} = 3.3 \text{ V} \pm 0.3 \text{ V}$		100		100	ns/V	
ΔυΔν	Input transition rise or fall rate	$V_{CC} = 5 V \pm 0.5 V$		20		20		
TA	Operating free-air temperature		-55	125	-40	85	°C	

NOTE 3: Unused inputs must be held high or low to prevent them from floating.

electrical characteristics over recommended operating free-air temperature range (unless otherwise noted)

DADAMETED	TEST COMPLIANCE	\ \ \ \ \ \ \ \ \ \ \ \ \ \ \ \ \ \ \	Т,	Δ = 25°C	;	SN54A	HC541	SN74AI	HC541	LINUT	
PARAMETER	TEST CONDITIONS	VCC	MIN	TYP	MAX	MIN	MAX	MIN	MAX	UNIT	
		2 V	1.9	2		1.9		1.9			
	ΙΟΗ = -50 μΑ	3 V	2.9	3		2.9		2.9			
V _{OH}		4.5 V	4.4	4.5		4.4		4.4		V	
	$I_{OH} = -4 \text{ mA}$	3 V	2.58			2.48		2.48			
	I _{OH} = -8 mA	4.5 V	3.94			3.8		3.8			
					0.1		0.1		0.1		
	Ι _{ΟL} = 50 μΑ	3 V			0.1		0.1		0.1	V	
V _{OL}		4.5 V			0.1		0.1		0.1		
	I _{OL} = 4 mA	3 V			0.36		0.5		0.44		
	I _{OL} = 8 mA	4.5 V			0.36		0.5		0.44		
Data inputs	V V OND	5.5.7			±0.1		±1		±1		
Control inputs	$V_I = V_{CC}$ or GND	5.5 V			±0.1		±1		±1	μΑ	
loz†	$V_O = V_{CC}$ or GND, $V_I (\overline{OE}) = V_{IL}$ or V_{IH}	5.5 V			±0.25		±2.5		±2.5	μΑ	
ICC	$V_I = V_{CC}$ or GND, $I_O = 0$	5.5 V			4		40		40	μΑ	
C _i	V _I = V _{CC} or GND	5 V		2	10				10	pF	
Co	$V_O = V_{CC}$ or GND	5 V		4					, and the second	pF	

[†] For input and ouput, IOZ includes the input leakage current.



SN54AHC541, SN74AHC541 OCTAL BUFFERS/DRIVERS WITH 3-STATE OUTPUTS

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switching characteristics over recommended operating free-air temperature range, V_{CC} = 3.3 V \pm 0.3 V (unless otherwise noted) (see Figure 1)

	FDOM	TO LOAD	SN	54AHC5	41	11		
PARAMETER	FROM (INPUT)	(OUTPUT)	CAPACITANCE	T _A = 25°	С	MIN	MAX	UNIT
	(5.7)	(5511 51)		MIN TYP	MAX	IVIIIN	WAX	
^t PLH*	А	Y	C _L = 15 pF	5	7	1	8.5	ns
^t PHL*	A	ī	CL = 15 pr	5	7	1	8.5	115
^t PZH*	<u>OE</u>	Y	C _L = 15 pF	6	10.5	1	11	20
^t PZL*	OE	ī		6	10.5	1	11	ns
^t PHZ*		ŌĒ Y	C _I = 15 pF	7	11	1	12	ns
^t PLZ*	OE		C[= 13 pr	7	11	1	12	113
^t PLH	А	Y	C _I = 50 pF	7.5	10.5	1	12	ns
^t PHL	A	ī	C[= 50 pr	7.5	10.5	1	12	115
^t PZH	<u>OE</u>	Y	C: 50 pF	8	14	1	16	
^t PZL	OE OE	ſ	Y $C_L = 50 \text{ pF}$	8	14	1	16	ns
^t PHZ	ŌĒ	V	C: - 50 pF	9	15.4	1	17.5	no
^t PLZ) OE	Y $C_L = 50 \text{ pF}$		9	15.4	1	17.5	ns

^{*} On products compliant to MIL-PRF-38535, this parameter is ensured but not production tested.

switching characteristics over recommended operating free-air temperature range, V_{CC} = 3.3 V \pm 0.3 V (unless otherwise noted) (see Figure 1)

5 5	•	, ,							
					SN	74AHC5	41		
PARAMETER	FROM (INPUT)	TO (OUTPUT)	LOAD CAPACITANCE	T _A = 25°C			MIN	MAX	UNIT
	(5.7)	(0011 01)		MIN T	ГΥР	MAX	IVIIIV	WAX	
^t PLH	А	Y	C _L = 15 pF		5	7	1	8.5	ns
t _{PHL}	A	ī	CL = 15 pr		5	7	1	8.5	115
^t PZH	OE	Y	C _I = 15 pF		6	10.5	1	11	ns
^t PZL	OE		OL = 13 pr		6	10.5	1	11	115
^t PHZ	ŌĒ	Y	C _L = 15 pF		7	11	1	12	ns
^t PLZ	OE		OL = 13 pr		7	11	1	12	113
^t PLH	А	Y	C _L = 50 pF		7.5	10.5	1	12	ns
^t PHL	^	Y CL = 50 pF		7.5	10.5	1	12	115	
^t PZH	OE	Y	C _L = 50 pF		8	14	1	16	ns
t _{PZL}	OE	Ι ΟΕ = 30 μι			8	14	1	16	115
^t PHZ	ŌĒ	Y	C _L = 50 pF		9	15.4	1	17.5	ns
^t PLZ		1	OL = 30 pr		9	15.4	1	17.5	110

switching characteristics over recommended operating free-air temperature range, V_{CC} = 5 V \pm 0.5 V (unless otherwise noted) (see Figure 1)

	5004		1015		SNS	54AHC5	41		
PARAMETER	FROM (INPUT)	TO (OUTPUT)	LOAD CAPACITANCE	T _A = 25°C			MIN	MAX	UNIT
	(111 51)	, ,		MIN T	ГҮР	MAX	IVIIIV	IVIAA	
^t PLH*	А	Y	C _L = 15 pF		3.5	5	1	6	ns
^t PHL*	A	CL = 15 pF		3.5	5	1	6	115	
^t PZH*	OE	Y	C _L = 15 pF		4.7	7.2	1	8.5	ns
^t PZL*	OE	Ĭ	1		4.7	7.2	1	8.5	115
^t PHZ*	ŌĒ	Y	C _I = 15 pF		5	7.5	1	8	ns
^t PLZ*	OE	ι Θ[=13 μι	OL = 13 pr		5	7.5	1	8	115
^t PLH	А	Y	C _L = 50 pF		5	7	1	8	ns
^t PHL	A	A Y			5	7	1	8	115
^t PZH	ŌĒ	Υ	C: - 50 pF		6.2	9.2	1	10.5	20
^t PZL	OE .	r	C _L = 50 pF		6.2	9.2	1	10.5	ns
^t PHZ	ŌĒ		C: - 50 pF		6	8.8	1	10	20
^t PLZ	OE	Y C _L = 50 pF			6	8.8	1	10	ns

^{*} On products compliant to MIL-PRF-38535, this parameter is ensured but not production tested.

switching characteristics over recommended operating free-air temperature range, V_{CC} = 5 V \pm 0.5 V (unless otherwise noted) (see Figure 1)

	5004	T0	1015	SN	74AHC5	41		
PARAMETER	FROM (INPUT)	TO (OUTPUT)	LOAD CAPACITANCE	T _A = 25°C	;	MIN	MAX	UNIT
	(51)	(3011 01)		MIN TYP	MAX	IVIIIN	WAX	
^t PLH	А	Y	C _L = 15 pF	3.5	5	1	6	ns
^t PHL	٨	ı	GL = 13 pr	3.5	5	1	6	110
^t PZH	ŌĒ	Y	C _I = 15 pF	4.7	7.2	1	8.5	ns
^t PZL	OE	CL = 15 pF	4.7	7.2	1	8.5	115	
^t PHZ	OE	Υ	C _L = 15 pF	5	7.5	1	8	ns
tPLZ	OE	ī	OL = 15 pr	5	7.5	1	8	113
^t PLH	А	Y	C 50 pF	5	7	1	8	ns
t _{PHL}	A	Y C _L = 50 pF		5	7	1	8	110
^t PZH	<u>OE</u>	Y	C: 50 pF	6.2	9.2	1	10.5	
^t PZL	OE	Y CL = 50	C _L = 50 pF	6.2	9.2	1	10.5	ns
^t PHZ	ŌĒ	Y	C _L = 50 pF	6	8.8	1	10	ns
tPLZ	OE .	r	GL = 50 pF	6	8.8	1	10	115

output-skew characteristics, C_L = 50 pF (see Note 4)

								SN74A	HC541	
PARAMETER	FROM (INPUT)	(OUTPUT)		T _A = 25°C	MIN MAX	UNIT				
	(141 01)		MIN MAX	MIN MAX						
*	٨	V	$3.3~\text{V}\pm0.3~\text{V}$	1.5	1.5					
^t sk(o)	А	ſ	5 V ± 0.5 V	1	1	ns				

NOTE 4: Characteristics are determined during product characterization and ensured by design.



noise characteristics, $V_{CC} = 5 \text{ V}$, $C_L = 50 \text{ pF}$, $T_A = 25^{\circ}\text{C}$ (see Note 5)

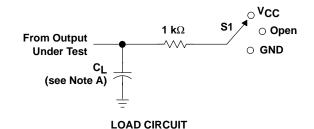
	PARAMETER				
V _{OL(P)}	Quiet output, maximum dynamic V _{OL}		0.8	V	
V _{OL(V)}	Quiet output, minimum dynamic V _{OL}		-0.8	V	
VOH(V)	Quiet output, minimum dynamic VOH	4.7		V	
VIH(D)	High-level dynamic input voltage	3.5		V	
V _{IL(D)}	Low-level dynamic input voltage		1.5	V	

NOTE 5: Characteristics are determined during product characterization and ensured by design for surface-mount packages only.

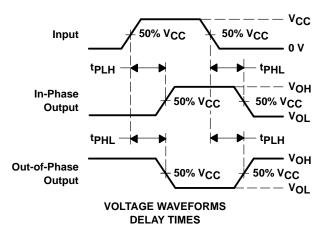
operating characteristics, $V_{CC} = 5 \text{ V}$, $T_A = 25^{\circ}\text{C}$

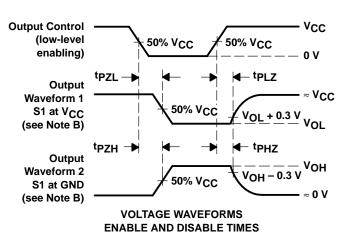
	PARAMETER		ONDITIONS	TYP	UNIT
C _{pd}	Power dissipation capacitance	No load,	f = 1 MHz	12	pF

PARAMETER MEASUREMENT INFORMATION



TEST	S 1
tPLH/tPHL	Open
tPLZ/tPZL	VCC
tPHZ/tPZH	GND





NOTES: A. C_L includes probe and jig capacitance.

- B. Waveform 1 is for an output with internal conditions such that the output is low except when disabled by the output control. Waveform 2 is for an output with internal conditions such that the output is high except when disabled by the output control.
- C. All input pulses are supplied by generators having the following characteristics: PRR \leq 1 MHz, $Z_O = 50 \Omega$, $t_f = 3$ ns. $t_f = 3$ ns.
- D. The outputs are measured one at a time with one input transition per measurement.

Figure 1. Load Circuit and Voltage Waveforms



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